TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WG34FU,TC7WG34FK

#### **Triple NON-Inverter**

#### **Features**

High output current : ±8 mA (min) at V<sub>CC</sub> = 3 V

• Super high speed operation: t<sub>pd</sub> = 2.7 ns (typ.)

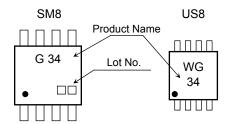
at  $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$ 

• Operating voltage range : V<sub>CC</sub> = 0.9 to 3.6 V

• 5.5-V tolerant inputs

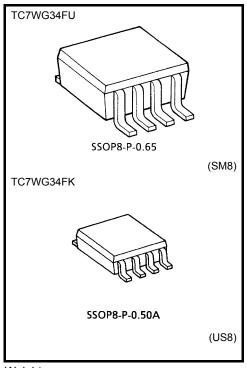
• 3.6-V power down protection outputs

#### Marking



## Absolute Maximum Ratings (Ta = 25°C)

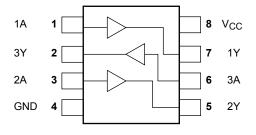
Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>C</sub> C	-0.5 to 4.6	V
DC input voltage	V <sub>IN</sub>	−0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to 4.6 (Note1)	.,
		-0.5 to VCC+0.5 (Note2)	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	lok	-20 (Note3)	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /GND current	Icc	±50	mA
Power dissipation	P <sub>D</sub>	300 (SM8) 200 (US8)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C



Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

## Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 V$ 

Note 2: High or Low State. Do not exceed I<sub>OUT</sub> of absolute maximum ratings.

Note 3: VOUT < GND

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## **IEC Logic Symbol**

### **Truth Table**



Α	Υ
L	L
Н	Н

## **Operating Ranges**

Characteristics	Symbol	Rating	Unit		
Supply voltage	V <sub>CC</sub>	0.9 to 3.6	V		
Input voltage	V <sub>IN</sub>	0 to 5.5	V		
Output voltage	V	0 to 3.6 (Note 4)	V		
	V <sub>OUT</sub>	0 to V <sub>CC</sub> (Note 5)	V		
Output current		± 8.0 (Note 6)			
	I <sub>OH</sub> /I <sub>OL</sub>	± 4.0 (Note 7)	mA		
		± 3.0 (Note 8)			
		± 1.7 (Note 9)			
		± 0.3 (Note 10)			
		± 0.02 (Note 11)			
Operating temperature	T <sub>opr</sub>	-40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 12)	ns/V		

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$ 

Note 9:  $V_{CC} = 1.4 \text{ to } 1.6 \text{ V}$ 

Note 10:  $V_{CC} = 1.1 \text{ to } 1.3 \text{ V}$ 

Note 11:  $V_{CC} = 0.9 \text{ V}$ 

Note 12:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



## **Electrical Characteristics**

### **DC Characteristics**

Characteristics Symbol Test Condition			Condition		Ta = 25°C		;	Ta = -40 to 85°C		Unit
Characteristics Symbol		Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
High-level input V <sub>II</sub>				0.9	$V_{CC}$	_	_	V <sub>CC</sub>	_	
		_		1.1 to 1.3	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	_	V
	V <sub>IH</sub>			1.4 to 1.6	V <sub>CC</sub> × 0.65		_	V <sub>CC</sub> × 0.65	_	
				1.65 to 1.95	V <sub>CC</sub> × 0.65	ı	_	V <sub>CC</sub> × 0.65	_	
				2.3 to 2.7	1.7	_	_	1.7	_	
				3.0 to 3.6	2.0		_	2.0	_	
				0.9		_	GND	_	GND	
Low-level input voltage							V <sub>CC</sub> × 0.3	_	V <sub>CC</sub> × 0.3	
	V <sub>IL</sub>		_	1.4 to 1.6	١	١	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35	V
				1.65 to 1.95	ı	١	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35	
				2.3 to 2.7			0.7		0.7	
				3.0 to 3.6			0.8		0.8	
		V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> =-0.02 mA	0.9	0.75		_	0.75	_	V
High-level output			$I_{OH} = -0.3 \text{ mA}$	1.1 to 1.3	V <sub>CC</sub> × 0.75	١	_	V <sub>CC</sub> × 0.75		
	V <sub>OH</sub>		$I_{OH} = -1.7 \text{ mA}$	1.4 to 1.6	V <sub>CC</sub> × 0.75	ı	_	V <sub>CC</sub> × 0.75	_	
voltage			$I_{OH} = -3.0 \text{ mA}$	1.65 to 1.95	V <sub>CC</sub> -0.45	I	_	V <sub>CC</sub> -0.45		
			$I_{OH} = -4.0 \text{ mA}$	2.3 to 2.7	2.0		_	2.0	_	
			$I_{OH} = -8.0 \text{ mA}$	3.0 to 3.6	2.48		_	2.48	_	
			$I_{OL} = 0.02 \text{ mA}$	0.9			0.1		0.1	V
Low-level output V <sub>O</sub>			$I_{OL} = 0.3 \text{ mA}$	1.1 to 1.3			V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
	V <sub>OL</sub>	$V_{IN} = V_{IL}$	I <sub>OL</sub> = 1.7 mA	1.4 to 1.6			V <sub>CC</sub> × 0.25		V <sub>CC</sub> × 0.25	
			I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	_	_	0.45	_	0.45	
			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7			0.4	_	0.4	
			I <sub>OL</sub> = 8.0 mA	3.0 to 3.6		_	0.4	_	0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5V		0 to 3.6		_	±0.1	_	±1.0	μΑ
Power off leakage current	l <sub>OFF</sub>	V <sub>IN</sub> = 0 to 5.5V V <sub>OUT</sub> = 0 to 3.6V		0		_	1.0	_	10.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		3.6	_	_	1.0	_	10.0	μΑ

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## AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C		Unit	
Ondracteristics Sylli		rest Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Offic
		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	24.4	_	_	_	
			1.1 to 1.3	_	11.6	21.7	1.0	40.5	
			1.4 to 1.6	_	6.5	9.8	1.0	11.6	
			1.65 to 1.95	_	4.9	7.0	1.0	7.6	
			2.3 to 2.7	_	3.2	4.4	1.0	4.9	
			3.0 to 3.6	_	2.4	3.5	1.0	4.1	
			0.9	_	26.9		_	_	
	<sup>t</sup> pLH <sup>t</sup> pHL	$C_L$ = 15 pF, $R_L$ = 1 M $\Omega$	1.1 to 1.3	_	12.7	24.2	1.0	42.1	ns
			1.4 to 1.6	_	7.1	10.7	1.0	12.9	
Propagation delay time			1.65 to 1.95	_	5.3	7.5	1.0	7.7	
			2.3 to 2.7	_	3.5	4.8	1.0	5.5	
			3.0 to 3.6	_	2.7	3.8	1.0	4.4	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	37.0	1	_	_	
			1.1 to 1.3	_	17.1	33.9	1.0	64.1	
			1.4 to 1.6	_	9.3	14.3	1.0	17.4	
			1.65 to 1.95	_	6.9	9.8	1.0	10.2	
			2.3 to 2.7	_	4.6	6.2	1.0	6.6	
			3.0 to 3.6	_	3.7	4.8	1.0	5.2	
Input capacitance	C <sub>IN</sub>	_	3.6	_	3		_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note13)	0.9 to 3.6	_	10	_	_	_	pF

Note 13: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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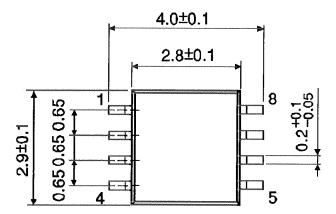
Average operating current can be obtained by the equation:

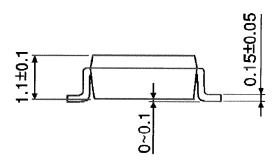
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$ 



## **Package Dimensions**

SSOP8-P-0.65 Unit: mm



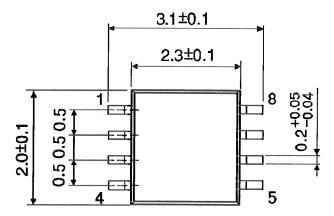


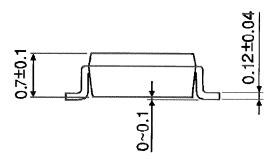
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Weight: 0.02 g (typ.)

# **Package Dimensions**

SSOP8-P-0.50A Unit: mm





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Weight: 0.01 g (typ.)

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